

# C6D04065A

## Silicon Carbide Schottky Diode

### Z-REC<sup>®</sup> RECTIFIER

$V_{RRM}$	=	650 V
$I_F (T_c=160^\circ\text{C})$	=	4 A
$Q_c$	=	16 nC

#### Features

- New 6<sup>th</sup> Generation Technology
- Low Forward Voltage Drop ( $V_F$ )
- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- Low Leakage Current ( $I_L$ )
- Temperature-Independent Switching Behavior
- Positive Temperature Coefficient on  $V_F$

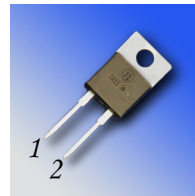
#### Benefits

- Higher System Level Efficiency
- Increase System Power Density
- Reduction of Heat Sink Requirements
- Parallel Devices Without Thermal Runaway

#### Applications

- Switch Mode Power Supplies (SMPS)
- Server/Telecom Power Supplies
- Industrial Power Supplies
- Solar
- UPS

#### Package



TO-220-2



Part Number	Package	Marking
C6D04065A	TO-220-2	C6D04065

#### Maximum Ratings ( $T_c = 25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter	Value	Unit	Test Conditions	Note
$V_{RRM}$	Repetitive Peak Reverse Voltage	650	V		
$V_{DC}$	DC Blocking Voltage	650	V		
$I_F$	Continuous Forward Current	18 9 4	A	$T_c=25^\circ\text{C}$ $T_c=125^\circ\text{C}$ $T_c=160^\circ\text{C}$	Fig. 3
$I_{FRM}$	Repetitive Peak Forward Surge Current	19 12	A	$T_c=25^\circ\text{C}, t_p=10\text{ ms, Half Sine Wave}$ $T_c=110^\circ\text{C}, t_p=10\text{ ms, Half Sine Wave}$	
$I_{FSM}$	Non-Repetitive Peak Forward Surge Current	32 28	A	$T_c=25^\circ\text{C}, t_p=10\text{ ms, Half Sine Wave}$ $T_c=110^\circ\text{C}, t_p=10\text{ ms, Half Sine Wave}$	Fig. 8
$I_{FMax}$	Non-Repetitive Peak Forward Surge Current	290 200	A	$T_c=25^\circ\text{C}, t_p=10\text{ }\mu\text{s, Pulse}$ $T_c=110^\circ\text{C}, t_p=10\text{ }\mu\text{s, Pulse}$	Fig. 8
$P_{tot}$	Power Dissipation	60 26	W	$T_c=25^\circ\text{C}$ $T_c=110^\circ\text{C}$	Fig. 4
$T_J, T_{stg}$	Operating Junction and Storage Temperature	-55 to +175	$^\circ\text{C}$		
	TO-220 Mounting Torque	1 8.8	Nm lbf-in	M3 Screw 6-32 Screw	

## Electrical Characteristics

Symbol	Parameter	Typ.	Max.	Unit	Test Conditions	Note
$V_F$	Forward Voltage	1.27 1.37	1.50 1.60	V	$I_F = 4\text{ A}$ $T_J = 25^\circ\text{C}$ $I_F = 4\text{ A}$ $T_J = 175^\circ\text{C}$	Fig. 1
$I_R$	Reverse Current	2 12	20 80	$\mu\text{A}$	$V_R = 650\text{ V}$ $T_J = 25^\circ\text{C}$ $V_R = 650\text{ V}$ $T_J = 175^\circ\text{C}$	Fig. 2
$Q_C$	Total Capacitive Charge	16		nC	$V_R = 400\text{ V}$ , $I_F = 4\text{ A}$ $T_J = 25^\circ\text{C}$	Fig. 5
C	Total Capacitance	256 32 27		pF	$V_R = 0\text{ V}$ , $T_J = 25^\circ\text{C}$ , $f = 1\text{ MHz}$ $V_R = 200\text{ V}$ , $T_J = 25^\circ\text{C}$ , $f = 1\text{ MHz}$ $V_R = 400\text{ V}$ , $T_J = 25^\circ\text{C}$ , $f = 1\text{ MHz}$	Fig. 6
$E_C$	Capacitance Stored Energy	2.6		$\mu\text{J}$	$V_R = 400\text{ V}$	Fig. 7

Note: This is a majority carrier diode, so there is no reverse recovery charge.

## Thermal Characteristics

Symbol	Parameter	Typ.	Unit	Note
$R_{\theta JC}$	Thermal Resistance from Junction to Case	2.5	$^\circ\text{C}/\text{W}$	Fig. 9

## Typical Performance

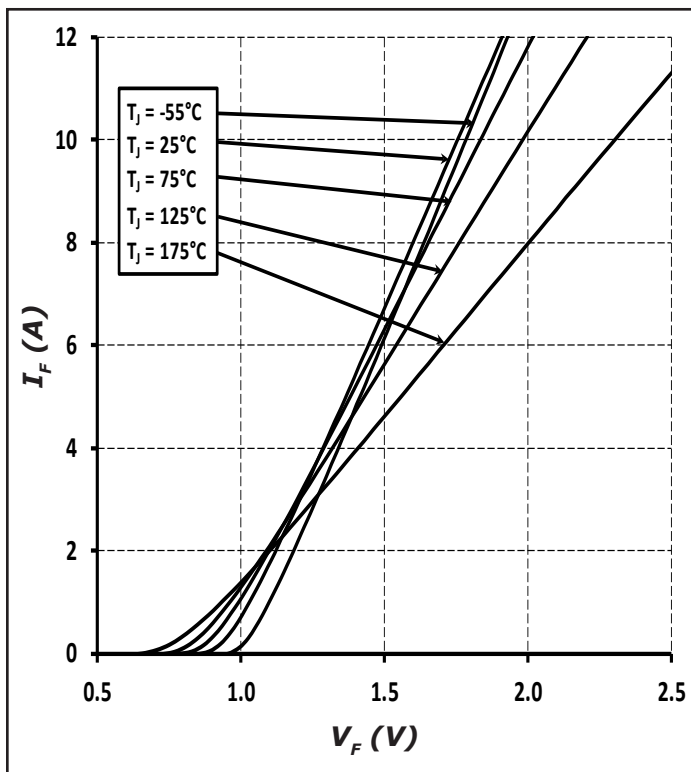


Figure 1. Forward Characteristics

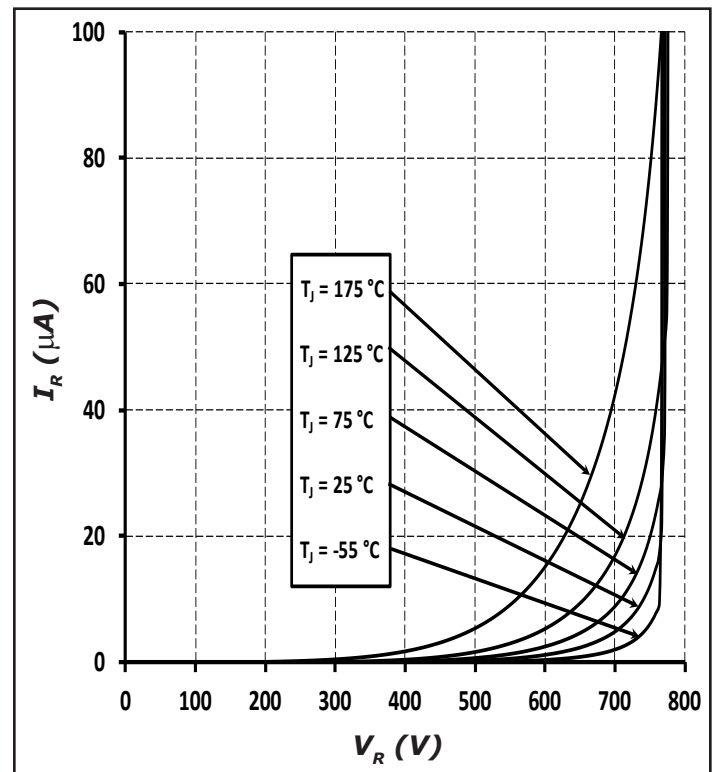


Figure 2. Reverse Characteristics

## Typical Performance

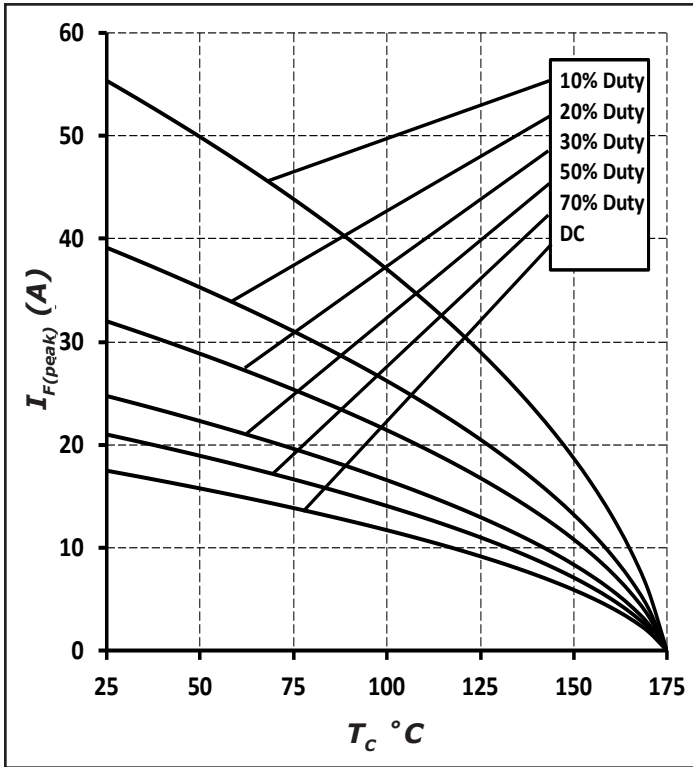


Figure 3. Current Derating

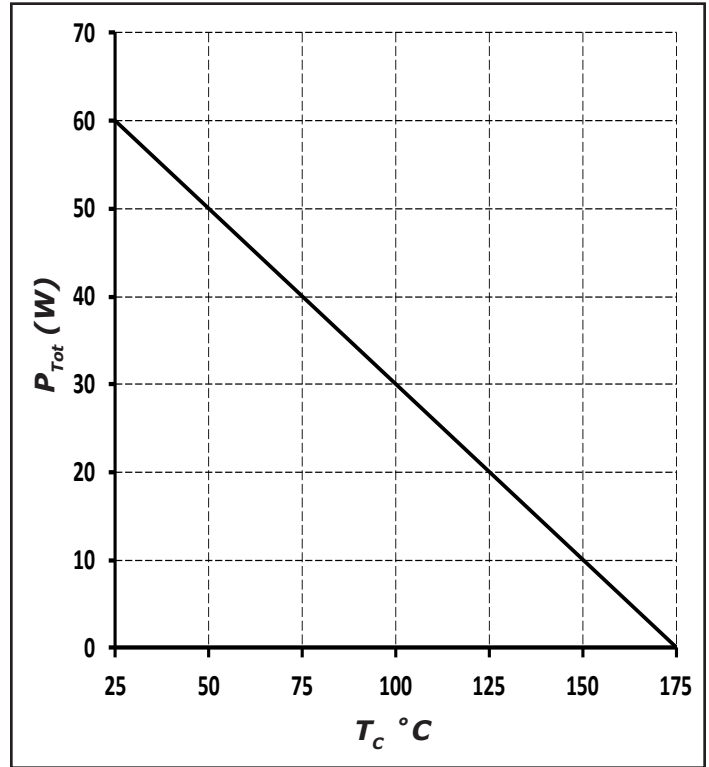


Figure 4. Power Derating

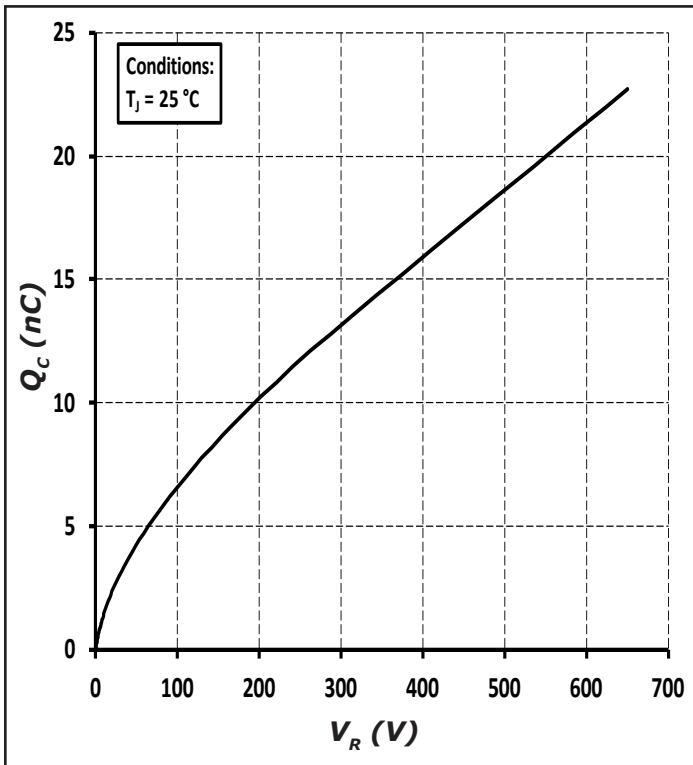


Figure 5. Total Capacitance Charge vs. Reverse Voltage

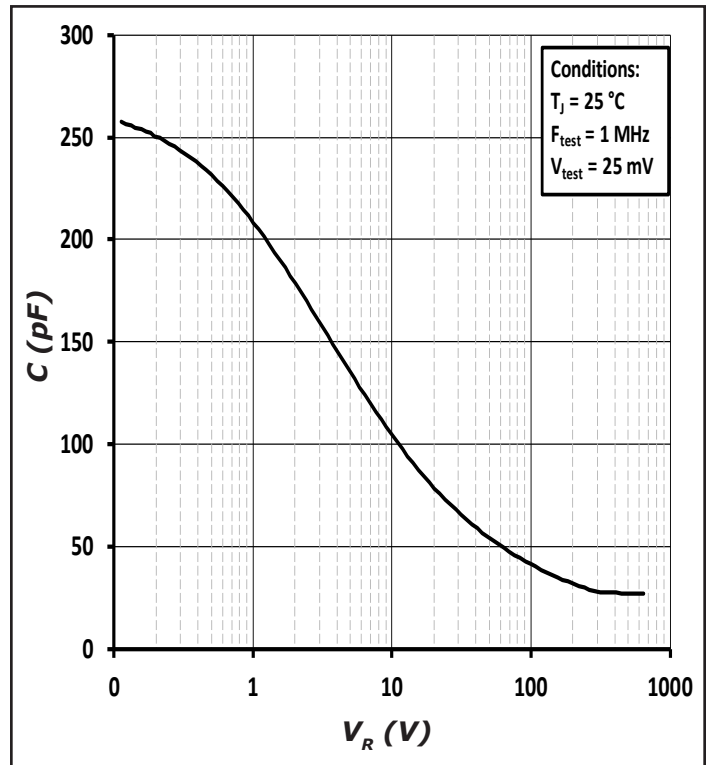


Figure 6. Capacitance vs. Reverse Voltage

## Typical Performance

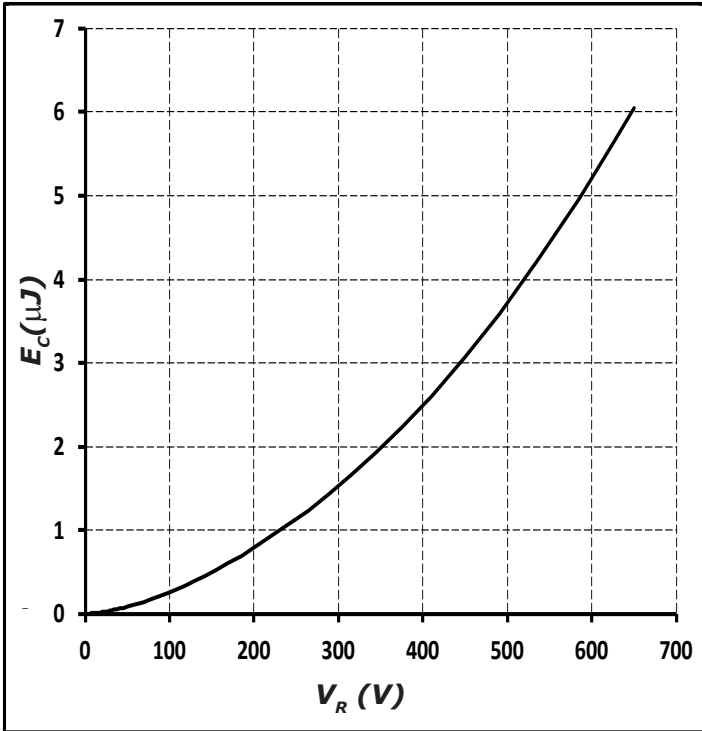


Figure 7. Capacitance Stored Energy

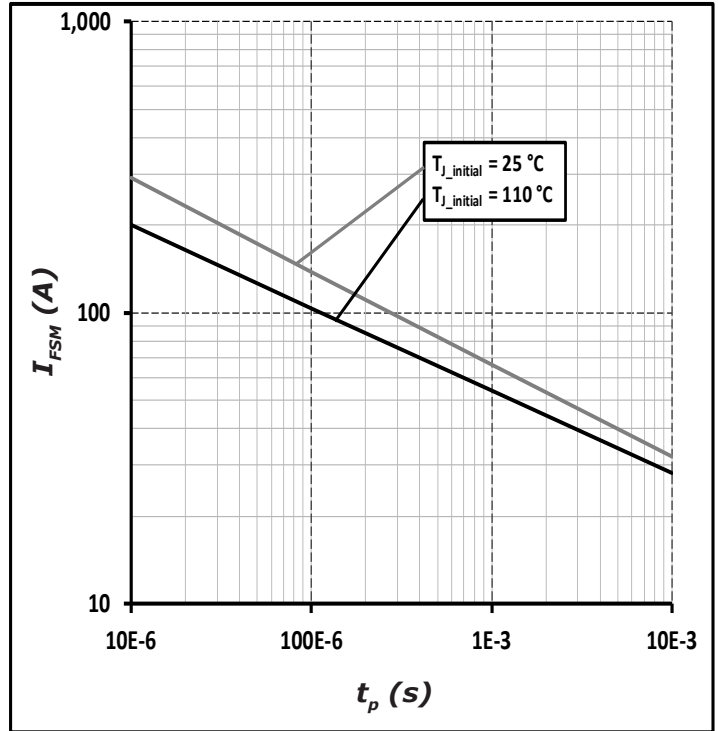


Figure 8. Non-repetitive peak forward surge current versus pulse duration (sinusoidal waveform)

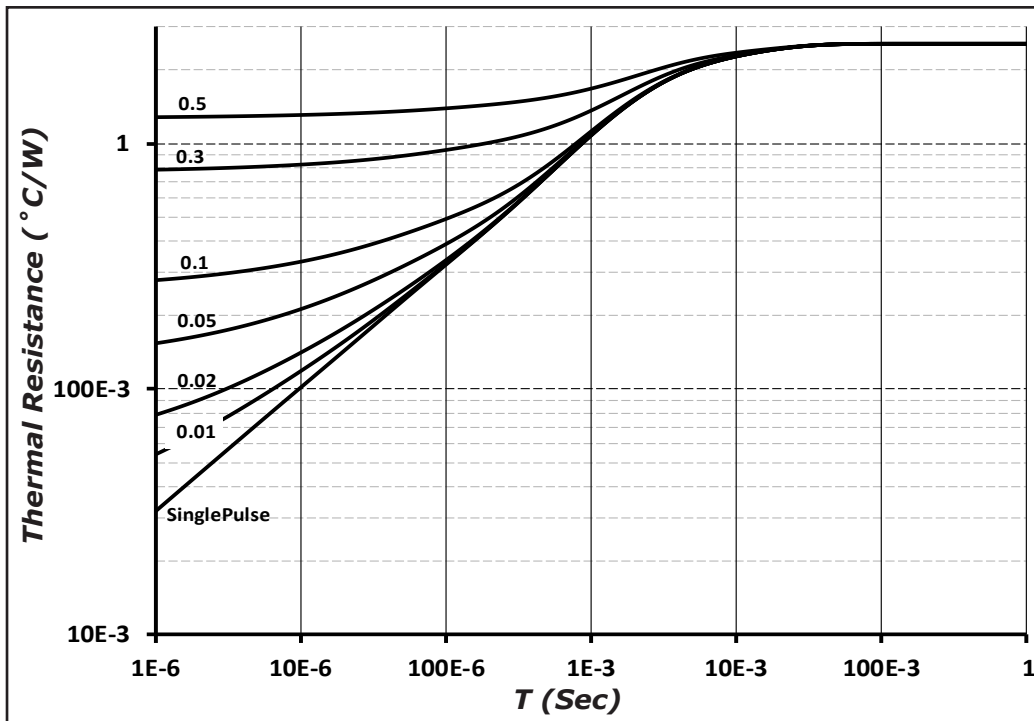
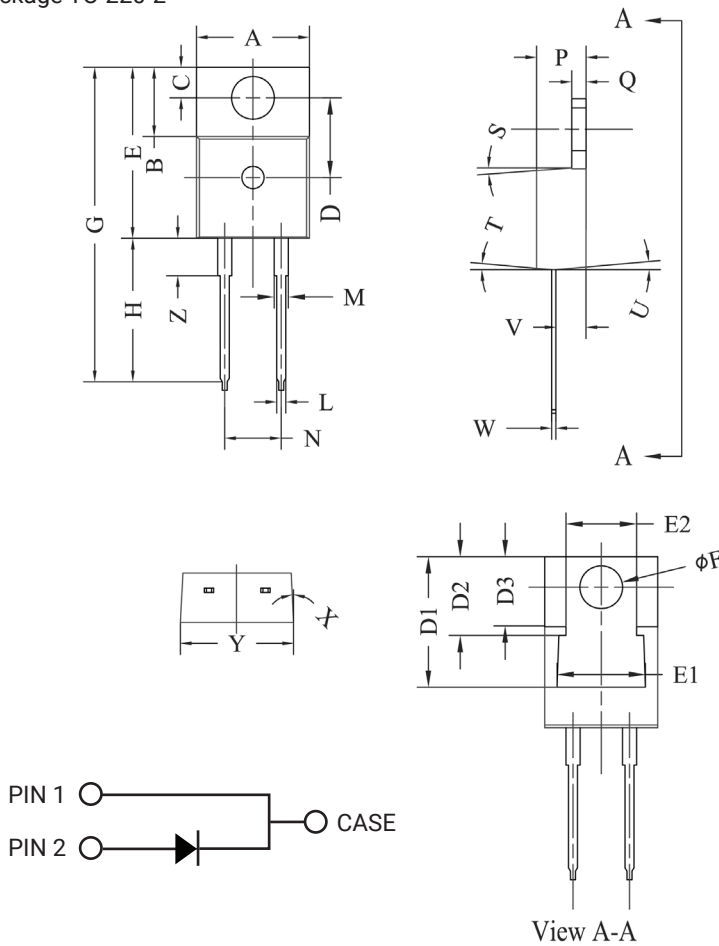


Figure 9. Transient Thermal Impedance

## Package Dimensions

### Package TO-220-2

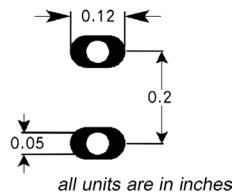


POS	Inches		Millimeters	
	Min	Max	Min	Max
A	.381	.410	9.677	10.414
B	.235	.255	5.969	6.477
C	.100	.120	2.540	3.048
D	.223	.337	5.664	8.560
D1	.457-.490		11.60-12.45 typ	
D2	.277-.303 typ		7.04-7.70 typ	
D3	.244-.252 typ		6.22-6.4 typ	
E	.590	.615	14.986	15.621
E1	.302	.326	7.68	8.28
E2	.227	.251	5.77	6.37
F	.143	.153	3.632	3.886
G	1.105	1.147	28.067	29.134
H	.500	.550	12.700	13.970
L	.025	.036	.635	.914
M	.045	.055	1.143	1.550
N	.195	.205	4.953	5.207
P	.165	.185	4.191	4.699
Q	.048	.054	1.219	1.372
S	3°	6°	3°	6°
T	3°	6°	3°	6°
U	3°	6°	3°	6°
V	.094	.110	2.388	2.794
W	.014	.025	.356	.635
X	3°	5.5°	3°	5.5°
Y	.385	.410	9.779	10.414
Z	.130	.150	3.302	3.810

NOTE:

1. Dimension L, M, W apply for Solder Dip Finish

## Recommended Solder Pad Layout



TO-220-2

Part Number	Package	Marking
C6D04065A	TO-220-2	C6D04065

Note: Recommended soldering profiles can be found in the applications note here:  
[http://www.wolfspeed.com/power\\_app\\_notes/soldering](http://www.wolfspeed.com/power_app_notes/soldering)



## Notes

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- **RoHS Compliance**

The levels of RoHS restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2011/65/EC (RoHS2), as implemented January 2, 2013. RoHS Declarations for this product can be obtained from your Wolfseed representative or from the Product Ecology section of our website at <http://www.wolfseed.com/Power/Tools-and-Support/Product-Ecology>.

- **REACH Compliance**

REACH substances of high concern (SVHCs) information is available for this product. Since the European Chemical Agency (ECHA) has published notice of their intent to frequently revise the SVHC listing for the foreseeable future, please contact a Cree representative to insure you get the most up-to-date REACH SVHC Declaration. REACH banned substance information (REACH Article 67) is also available upon request.

- This product has not been designed or tested for use in, and is not intended for use in, applications implanted into the human body nor in applications in which failure of the product could lead to death, personal injury or property damage, including but not limited to equipment used in the operation of nuclear facilities, life-support machines, cardiac defibrillators or similar emergency medical equipment, aircraft navigation or communication or control systems, or air traffic control systems.

## Related Links

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- Cree SiC Schottky diode portfolio: <http://www.wolfseed.com/Power/Products#SiCSchottkyDiodes>
- Schottky diode Spice models: <http://www.wolfseed.com/power/tools-and-support/DIODE-model-request2>
- SiC MOSFET and diode reference designs: <http://go.pardot.com/l/101562/2015-07-31/349i>